



JMD150KD18T1W



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Typical Electrical & Thermal Characteristics

FIG.1: Forward characteristics(per diode)

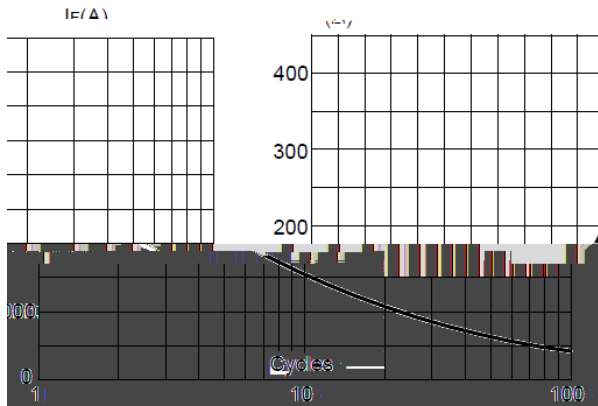
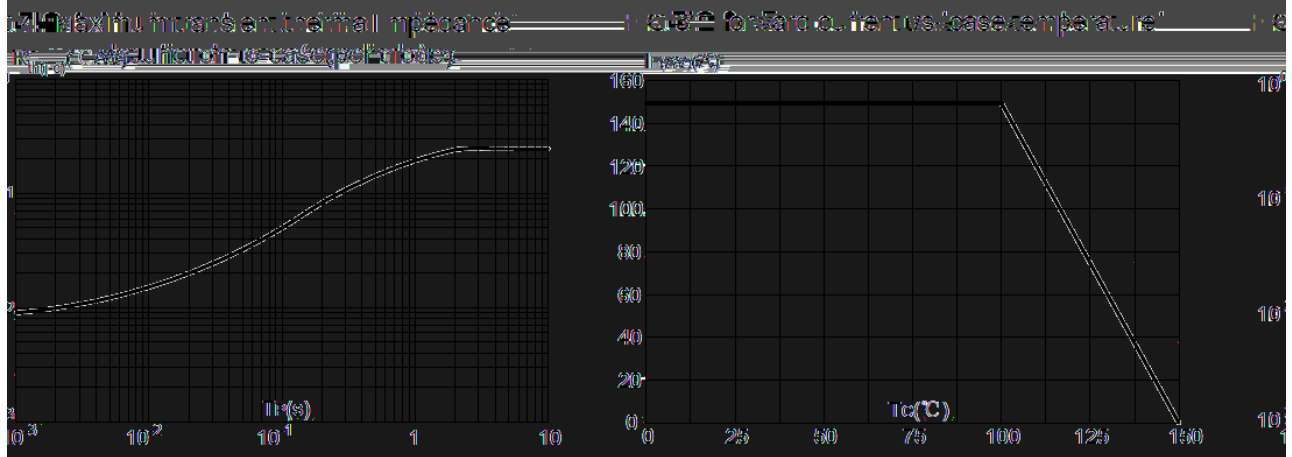
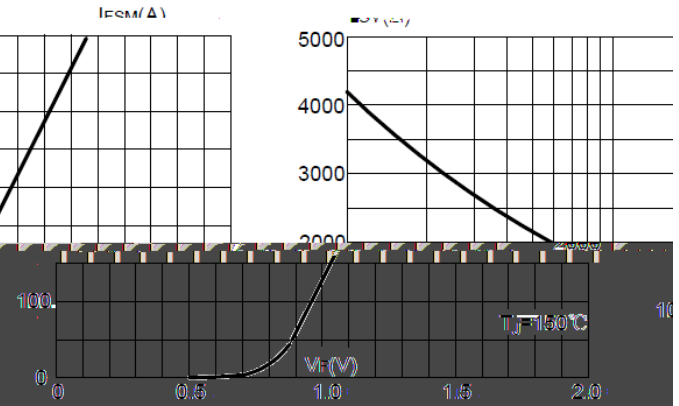
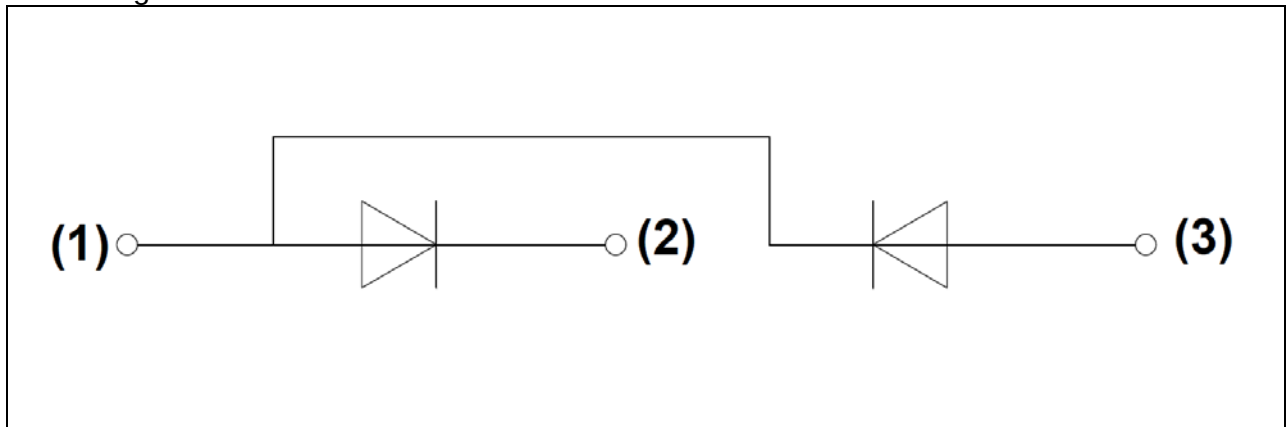


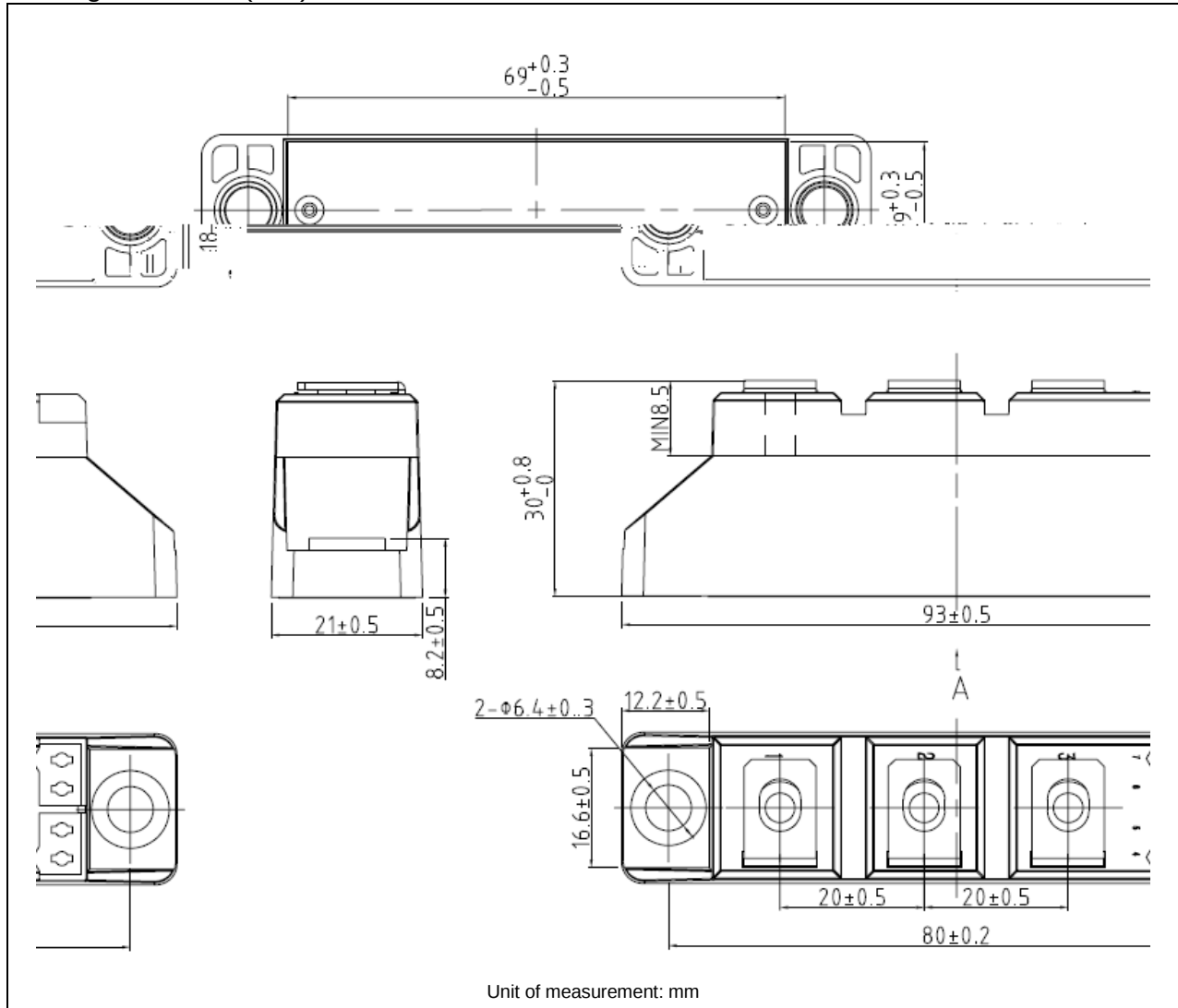
FIG.2: Peak on-state surge current



Circuit Diagram



Package Outlines (mm)





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